NSN 5961-01-108-3267



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-108-3267 **Inclosure Material:** Metal **Overall Length:** 0.250 inches **Terminal Length:** Between 0.500 inches and 0.800 inches **Overall Diameter:** 0.370 inches **End Application:** E-3a **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 collector to base voltage, dc and 300.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 15.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminal surface option gold **Test Data Document:** 97942-582r665 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead

N/a

Shelf Life:

Unit Of Measure:

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